

Generation Section

■ DC voltage generation

Range	Generation Range	Resolution	Max. Load Current	Accuracy (One Year) ±(% of setting + V + V ¹ I _o /I _s of the limiter range)	Temperature Coefficient ±(% of setting + V + V ¹ I _o /I _s of the limiter range)/°C
200 mV	±205.000 mV	1 µV	±3.2 A	0.02 + 200 µV + 80 µV (400 µV)	0.002 + 20 µV + 8 µV (40 µV)
2 V	±2.05000 V	10 µV	±3.2 A	0.02 + 300 µV + 100 µV (500 µV)	0.002 + 30 µV + 10 µV (50 µV)
12 V	±12.0000 V	100 µV	±3.2 A	0.02 + 2 mV + 800 µV (3 mV)	0.002 + 200 µV + 80 µV (300 µV)
20 V	±20.5000 V	100 µV	±2 A	0.02 + 2 mV + 800 µV (5 mV)	0.002 + 200 µV + 80 µV (500 µV)
30 V	±30.0000 V	1 mV	±2 A	0.02 + 20 mV + 5 mV (30 mV)	0.002 + 2 mV + 500 µV (3 mV)
60 V	±60.0000 V	1 mV	±1 A	0.02 + 20 mV + 6 mV (40 mV)	0.002 + 2 mV + 600 µV (4 mV)
110 V	±110.0000 V	1 mV	±0.5 A	0.02 + 20 mV + 8 mV (70 mV)	0.002 + 2 mV + 800 µV (7 mV)

The values inside the parentheses are those when the limiter range is 3 A.

■ DC current generation

Range	Max. Output	Resolution	Max. Load Voltage	Accuracy (One Year) ±(% of setting + A)	Temperature Coefficient ±(% of setting + A)/°C
20 µA	±20.5000 µA	100 pA	±110 V	0.03 + 50 nA	0.003 + 5 nA
200 µA	±205.0000 µA	1 nA	±110 V	0.03 + 300 nA	0.003 + 30 nA
2 mA	±2.05000 mA	10 nA	±110 V	0.03 + 3 µA	0.003 + 300 nA
20 mA	±20.5000 mA	100 nA	±110 V	0.03 + 30 µA	0.003 + 3 µA
200 mA	±205.0000 mA	1 µA	±110 V	0.03 + 300 µA	0.003 + 30 µA
0.5 A	±0.50000 A	10 µA	±110 V	0.03 + 5 mA	0.003 + 500 µA
1 A	±1.00000 A	10 µA	±60 V	0.03 + 5 mA	0.003 + 500 µA
2 A	±2.00000 A	10 µA	±30 V	0.03 + 5 mA	0.003 + 500 µA
3 A	±3.20000 A	10 µA	±12 V	0.03 + 5 mA	0.003 + 500 µA

Accuracy: One year accuracy at 23±5 °C

Temperature coefficient: Add the temperature coefficient at 5 to 18 °C and 28 to 40 °C.

■ Current limiter

Setting ^{*1}	Range	Resolution	Min. Setting
0.10 µA ~ 20.000 µA	20 µA	10 nA	10 nA
20.1 µA ~ 200.0 µA	200 µA	100 nA	100 nA
0.201 mA ~ 2.000 mA	2mA	1 µA	1 µA
2.01 mA ~ 20.00 mA	20mA	10 µA	10 µA
20.1 mA ~ 200.0 mA	200mA	100 µA	100 µA
0.201 A ~ 3.20 A	3.2A	1 mA	1 mA

*1 Larger of the two values |I_{Hi}| and |I_{Lo}| when |I_{Hi} limiter| ≠ |I_{Lo} limiter|

■ Voltage limiter

Setting ^{*1}	Range	Resolution	Min. Setting
1.0 mV ~ 200.0 mV	200 mV	100 µV	100 µV
0.201 V ~ 2.000 V	2 V	1 mV	1 mV
2.01 V ~ 20.00 V	20 V	10 mV	10 mV
20.1 V ~ 110.0 V	110 V	100 mV	100 mV

■ Transient response time (Typical)

Voltage generation

100 µs: Time to reach ±0.1% of final value *1

at 20 V range with the generation and limiter settings at maximum values and under the 25% pure resistive load

*1: In condition of zero voltage base pulse mode, measure delay time to reach ±0.1% of final value
Integration time 250 µs

Current generation

400 µs: Time to reach ±1% of final value *2

at 20 mA range with the generation and limiter settings at maximum values and under the pure resistive load

*2: In condition of zero current base pulse mode, measure delay time to reach ±1% of final value
Integration time 250 µs

■ Output Noise (Typical)

8 mVp-p (DC to 20 MHz)
(with generation at 2 V range and limiter at 1 A range)

Measurement Section

■ DC Voltage measurement

Range	Integration time 16.6ms/20ms,100ms,200ms				Integration time 4ms,1ms,250 μs			
	Measurement Range	Resolution	Accuracy (One Year) ±(% of reading + V)	Temperature Coefficient ±(% of reading + V) / °C	Measurement Range	Resolution	Accuracy (One Year) ±(% of reading + V)	Temperature Coefficient ±(% of reading + V) / °C
200 mV	±205.000 mV	1 μV	0.02 + 100 μV	0.002 + 10 μV	±205.00 mV	10 μV	0.02 + 200 μV (300 μV)	0.002 + 20 μV (30 μV)
2V	±2.05000 V	10 μV	0.02 + 200 μV	0.002 + 20 μV	±2.0500 V	100 μV	0.02 + 300 μV (500 μV)	0.002 + 30 μV (50 μV)
20 V	±20.5000 V	100 μV	0.02 + 1 mV	0.002 + 100 μV	±20.500 V	1 mV	0.02 + 3 mV (5 mV)	0.002 + 300 μV (500 μV)
110 V	±110.000 V	1 mV	0.02 + 10 mV	0.002 + 1 mV	±110.00 V	10 mV	0.02 + 30 mV (50 mV)	0.002 + 3 mV (5 mV)

■ DC Current measurement

Range	Integration time 16.6ms/20ms,100ms,200ms				Integration time 4ms,1ms, 250 μs			
	Measurement Range	Resolution	Accuracy (One Year) ±(% of reading + A)	Temperature Coefficient ±(% of reading + A) / °C	Measurement Range	Resolution	Accuracy (One Year) ±(% of reading + A)	Temperature Coefficient ±(% of reading + A) / °C
20 μA	±20.5000 μA	100 pA	0.03 + 50 nA	0.003 + 5 nA	±20.500 μA	1 nA	0.03 + 70 nA (80 nA)	0.003 + 7 nA (8 nA)
200 μA	±205.000 μA	1 nA	0.03 + 300 nA	0.003 + 30 nA	±205.00 μA	10 nA	0.03 + 350 nA (400 nA)	0.003 + 35 nA (40 nA)
2 mA	±2.05000 mA	10 nA	0.03 + 3 μA	0.003 + 300 nA	±2.0500 mA	100 nA	0.03 + 3.5 μA (4 μA)	0.003 + 350 nA (400 nA)
20 mA	±20.5000 mA	100 nA	0.03 + 30 μA	0.003 + 3 μA	±20.500 mA	1 μA	0.03 + 35 μA (40 μA)	0.003 + 3.5 μA (4 μA)
200 mA	±205.000 mA	1 μA	0.03 + 300 μA	0.003 + 30 μA	±205.00 mA	10 μA	0.03 + 350 μA (400 μA)	0.003 + 35 μA (40 μA)
3 A	±3.20000 A	10 μA	0.03 + 5 mA	0.003 + 500 μA	±3.2000 A	100 μA	0.03 + 5.5 mA (6 mA)	0.003 + 550 μA (600 μA)

Accuracy: One year accuracy at 23±5 °C Auto zero ON.

Temperature coefficient: Add the temperature coefficient at 5 to 18 °C and 28 to 40 °C.

Values inside the parentheses are those when the integration time is 1 ms or 250 μs.

Function

■ Generation

Generation function: Voltage or current

Generation mode: DC or pulse

Sweep mode: Linear, logarithmic, or program (up to 65535 steps)

■ Measurement

Measurement function: Voltage, current, and resistance

Measurement data storage: Up to 65535 data points

Average: Block average or moving average
(Specified count: 2 to 256)

■ Trigger

Trigger mode: Internal, external, and immediate

■ Time setting

Pulse width:	100 μs to 3600 s	1 μs resolution
Period time:	1 ms to 3600 s	1 μs resolution (during source and measure operation)
	100 μs to 3600 s	1 μs resolution (during source-only operation)
Source delay:	1 μs to 3600 s	1 μs resolution
Measurement delay:	1 μs to 3600 s	1 μs resolution
Integration time:	250 μs, 1 ms, 4 ms, 16.6 ms/20 ms, 100 ms (auto detect from the power supply frequency when the power is turned ON for 16.6 ms/20 ms)	

■ Computation function

Operators:	+[addition], -[subtraction], *[multiplication], / [division], and ^ [exponentiation]
Functions:	ABS(), EXP(), LN(), LOG(), SQRT(), SIN(), COS(), TAN(), ASIN(), ACOS(), ATAN(), SINH(), COSH(), TANH(), RAND()

■ Resistance calculation

Calculated from measured voltage/generated current or generated voltage/
measured current.

External Input/Output

Synchronization signal input/output section (TRIG/SWEEP/CTRL IN and OUT)

Connector type	BNC connector
I/O level	TTL
I/O logic format	Negative logic, falling edge
Minimum pulse width	10 μs or greater

External input/output section

Connector type	D-Sub 15-pin
I/O level	TTL
I/O logic format	Negative logic, falling edge
Minimum pulse width	10 μs or greater

GP-IB interface

Electrical and mechanical specifications
Conforms to IEEE St'd 488-1978

Functional specifications SH1, AH1, T6, L4, SR1, RL1, PP0, DC1, DT1, C0
Protocol Conforms to IEEE St'd 488.2-1992
Address 0 to 30

RS-232 interface

Connector type D-Sub 9-pin
Electrical specifications Conforms to EIA RS-232
Connection format Point-to-point
Transmission mode Full-duplex
Synchronization mode Start-stop synchronization
Baud rate 9600, 14400, 19200, 38400, 57600, or 115200 bps

USB interface

Number of ports 1
Connector type Type B connector (receptacle)
Electrical and mechanical specifications Conforms to USB Rev. 1.1

Ethernet interface (optional)

Number of communication ports 1
Connector type RJ-45 connector
Electrical and mechanical specifications Conforms to IEEE 802.3.
Transmission system 100BASE-TX/10BASE-T
Data rate 100 Mbps/10 Mbps

General Specifications

Display: 256 x 64 dots vacuum fluorescent display

Internal memory:

ROM: 4MB Area for storing setup and output pattern files
RAM: 4MB Area for storing the measured results
(cleared when the power is turned OFF)

Warm-up time: At least 60 minutes

Operating conditions: 5 to 40 °C, 20 to 80% RH

Rated supply voltage:

100 to 120 VAC or 220 to 240 VAC (automatic switching)

Rated supply frequency: 50/60 Hz

Maximum power consumption:

Approx. 200 VA

Max. common-mode voltage:
±250 Vpeak between the generation
(measurement)
terminal and case

Max. Output/ input voltage:

110 V between High and Low terminal.

1 V between Output and Sense terminal.

Weight: Approx. 7 kg

External dimensions: Approx. 213 (W) × 132 (H) × 400 (D) mm
(excluding projections)